



SURFACE MOUNT SCHOTTKY BARRIER DIODE

Product Summary

V _{RRM} (V)	I _O (mA)	V _{Fmax} (V)	I _{Rmax} (μΑ)
40	30	0.37	1

Description

30mA Surface Mount Schottky Barrier Diode in SOT-26 package, offers low capacitance and low forward voltage drop, designed with Guard Ring for Transient Protection. Ideal for low logic level applications.

Features and Benefits

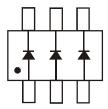
- Low Forward Voltage Drop
- Guard Ring Die Construction for Transient Protection
- Ideal for low logic level applications
- Low Capacitance
- Totally Lead-Free & Fully RoHS Compliant (Note 1 & 2)
 Halogen and Antimony Free. "Green" Device(Note 3)

Mechanical Data

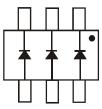
- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound,
 Note 5. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Polarity: See Diagram
- Leads: Matte Tin (Lead Free), Solderable per MIL-STD-202, Method 208 (§3)
- Lead Free Plating (Matte Tin Finish annealed over Copper leadframe).
- Weight: 0.016 grams (approximate)



Top View



SDM03MT40 Device Schematic



SDM03MT40A Device Schematic

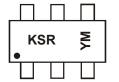
Ordering Information (Note 4)

Part Number	Case	Packaging
SDM03MT40-7-F	SOT26	3000/Tape & Reel
SDM03MT40A-7-F	SOT26	3000/Tape & Reel

Notes:

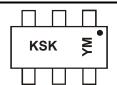
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



KSR = SDM03MT40 Product Type Marking Code

YM = Date Code Marking Y = Year ex: A = 2013 M = Month ex: 9 = September



KSK = SDM03MT40A Product Type Marking Code YM = Date Code Marking Y = Year ex: A = 2013 M = Month ex: 9 = September

Date Code Key

Year	2006	2007	2008	2009	2010	2011	2012	2 20	13	2014	2015
Code	Т	U	V	W	X	Υ	Z		Ą	В	С
Month	Jan	Feb	Mar	Apr Ma	y Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4 5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _R WM	40	V
RMS Reverse Voltage	V _{R(RMS)}	28	V
Forward Continuous Current (Note 6)	I _{FM}	30	mA
Non-Repetitive Peak Forward Surge Current @8.3ms Single half sine-wave superimposed on rated load (JEDEDC method)	I _{FSM}	200	mA

Thermal Characteristics

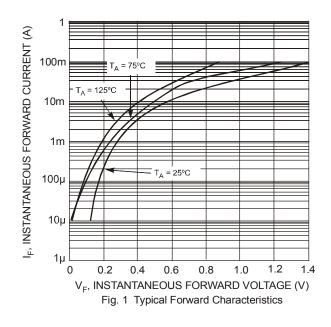
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_{D}	225	mW
Thermal Resistance, Junction to Ambient Air	$R_{ heta JA}$	444	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-40 to +125	°C

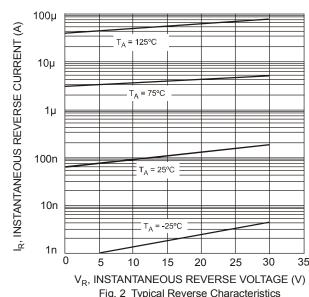
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 6)	V _{(BR)R}	40	_	_	V	I _R = 10μA
Forward Voltage Drop (Note 6)	V_{F}	_	_	370	mV	I _F = 1mA
Leakage Current (Note 6)	I _R	_	_	1	μA	V _R = 10V
Total Capacitance	Ст	_	2	_	pF	V _R = 1V f = 1.0 MHz

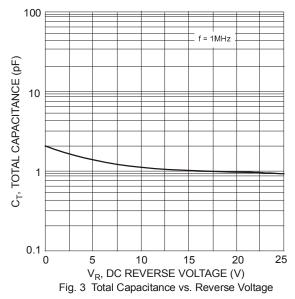
Notes:

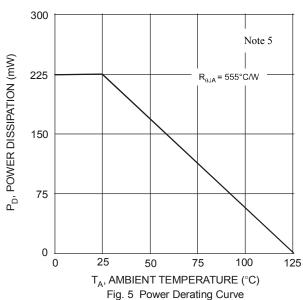
- 5. Device mounted on FR-4 PC board with recommended pad layout, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 6. Short duration pulse test used to minimize self-heating effect.











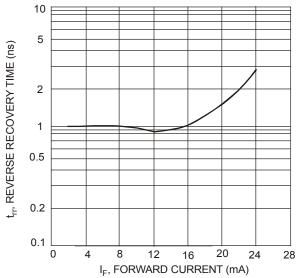
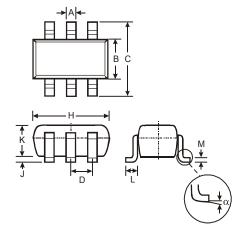


Fig. 4 Typical Reverse Recovery Time Characteristics

Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

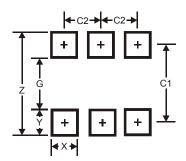


SOT26						
Dim	Min	Max	Тур			
Α	0.35	0.50	0.38			
В	1.50	1.70	1.60			
С	2.70	2.70 3.00 2.8				
D		_	0.95			
Н	2.90	3.10	3.00			
J	0.013	0.10	0.05			
K	1.00	1.30	1.10			
L	0.35	0.55	0.40			
M	0.10	0.20	0.15			
α	0°	8°	_			
All D	All Dimensions in mm					



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Y	0.80
C1	2.40
C2	0.95

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